CMOS Digital Integrated Circuits Silicon Monolithic

74VHC20FT

1. Functional Description

· Dual 4-Input NAND Gate

2. General

The 74VHC20FT is an advanced high speed CMOS 4-INPUT NAND GATE fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including a buffer output, which provide high noise immunity and stable output.

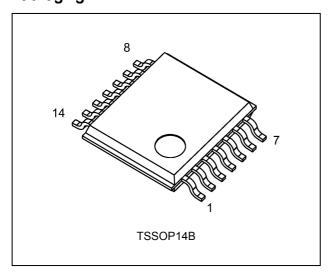
An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature: $T_{opr} = -40$ to 125 °C
- (3) High speed: $t_{pd} = 3.3 \text{ ns (typ.)}$ at $V_{CC} = 5.0 \text{ V}$
- (4) Low power dissipation: $I_{CC} = 2.0 \mu A \text{ (max)}$ at $T_a = 25 \text{ °C}$
- (5) High noise immunity: $V_{NIH} = V_{NIL} = 28 \% V_{CC}$ (min)
- (6) Power down protection is provided on all inputs.
- (7) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (8) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ V}$ to 5.5 V
- (9) Pin and function compatible with the 74 series (AC/HC/AHC/LV etc.) 20 type.

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

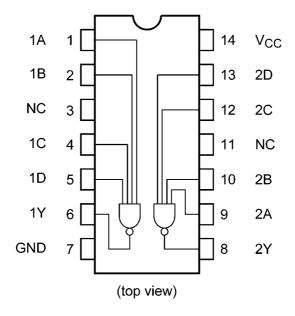
4. Packaging



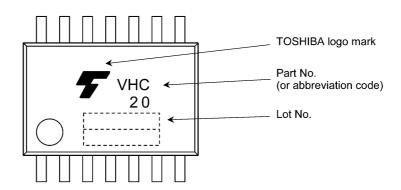
Start of commercial production



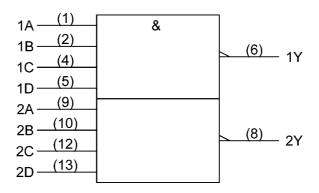
5. Pin Assignment



6. Marking



7. IEC Logic Symbol





8. Truth Table

Α	В	С	D	Y
L	Х	Х	Х	Н
Х	L	Х	Х	Н
Х	Х	L	Х	Н
Х	Х	Х	L	Н
Н	Н	Н	Н	L

X: Don't Care

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	V
Output voltage	V _{OUT}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		-20	mA
Output diode current	I _{OK}		±20	mA
Output current	I _{OUT}		±25	mA
V _{CC} /ground current	Icc		±50	mA
Power dissipation	P _D	(Note 1)	180	mW
Storage temperature	T _{stg}		-65 to 150	ç

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V _{CC}		2.0 to 5.5	V
Input voltage	V _{IN}		0 to 5.5	V
Output voltage	V _{OUT}		0 to V _{CC}	V
Operating temperature	T _{opr}		-40 to 125	°C
Input rise and fall times	dt/dv	V_{CC} = 3.3 \pm 0.3 V	0 to 100	ns/V
		V_{CC} = 5.0 ± 0.5 V	0 to 20	

Note: The operating ranges are required to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.



11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	_	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	_	
Low-level input voltage	V _{IL}	_		2.0	_	_	0.50	V
				3.0 to 5.5	_		$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I_{OH} = -4 mA	3.0	2.58	_	_	
			I _{OH} = -8 mA	4.5	3.94		_	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH}$	I _{OL} = 50 μA	2.0	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I _{OL} = 4 mA	3.0	_	_	0.36	
			I_{OL} = 8 mA	4.5	_		0.36	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_		±0.1	μΑ
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND	·	5.5	_	_	2.0	μΑ

11.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	ool Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	V
				3.0 to 5.5	V _{CC} × 0.7	_	
Low-level input voltage	V _{IL}	_		2.0	_	- 0.50	
				3.0 to 5.5	_	$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			I_{OH} = -4 mA	3.0	2.48	_	
			I_{OH} = -8 mA	4.5	3.80	_	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH}$	I _{OL} = 50 μA	2.0	ı	0.1	V
				3.0		0.1	
				4.5	_	0.1	
			I _{OL} = 4 mA	3.0	_	0.44	
			I _{OL} = 8 mA	4.5	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND	_	0 to 5.5	_	±1.0	μА
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	20.0	μА



11.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit		
High-level input voltage	V _{IH}	_		2.0	1.50	_	V		
						3.0 to 5.5	V _{CC} × 0.7	_	
Low-level input voltage	V _{IL}	_		2.0	_	- 0.50			
				3.0 to 5.5	_	$V_{CC} \times 0.3$			
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	_	V		
					2.9	_			
				4.5	4.4	_			
			I_{OH} = -4 mA	3.0	2.40	_			
			I_{OH} = -8 mA	4.5	3.70	_			
Low-level output voltage	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA	2.0		0.1	V		
				3.0		0.1			
				4.5	_	0.1			
			I _{OL} = 4 mA	3.0	_	0.55			
			I _{OL} = 8 mA	4.5	_	0.55			
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±2.0	μА		
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	40.0	μА		

11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

Characteristics	Symbol	Note	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		3.3 ± 0.3	15	1	4.6	6.6	ns
				50		7.1	10.1	
			5.0 ± 0.5	15	_	3.3	5.0	
				50	_	4.8	7.0	
Input capacitance	C _{IN}					4	10	pF
Power dissipation capacitance	C _{PD}	(Note 1)			1	19	_	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{|N} + I_{CC}/2 \text{ (per gate)}$

11.5. AC Characteristics

(Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

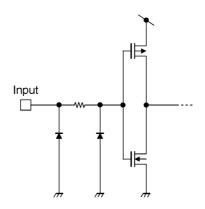
Characteristics	Symbol	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	3.3 ± 0.3	15	1.0	8.0	ns
			50	1.0	11.5	
		5.0 ± 0.5	15	1.0	6.0	
			50	1.0	8.0	
Input capacitance	C _{IN}				10	pF

11.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	3.3 ± 0.3	15	1.0	9.5	ns
			50	1.0	13.0	
		5.0 ± 0.5	15	1.0	7.0	
			50	1.0	9.0	
Input capacitance	C _{IN}			_	10	pF

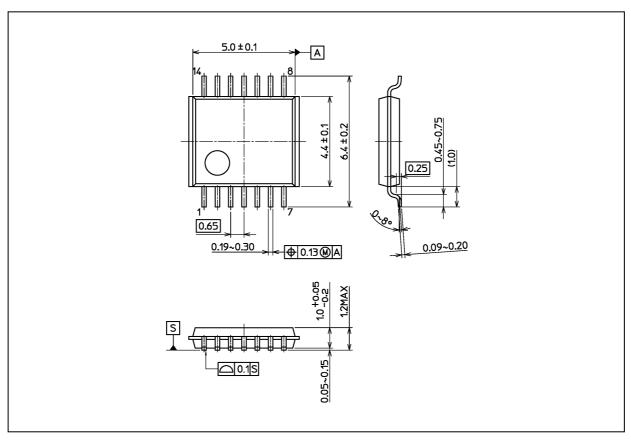


11.7. Equivalent Circuit



Package Dimensions

Unit: mm



Weight: 0.054 g (typ.)

Package Name(s)
Nickname: TSSOP14B



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